SUBJECT CODE NO:- H-160 FACULTY OF ENGINEERING AND TECHNOLOGY T.E. (EC/ECT/IEC/E&C)

Microcontroller & Advanced Processors (REVISED)

[Time:	Three Hours] [Max. Mark	s: 80
N.B	Please check whether you have got the right question paper. i. Question No 1 & 6 are compulsory ii. Answer any two questions from the remaining questions of each section iii. Assume suitable data whenever necessary Section- A	
Q.1	Solve any Two a) Find the physical address of memory locations referred to in the following instruction if DS=8000H, DI=143A,& SI=1A32 1. mov [DI],AL 2. mov[SI][704],AX 3. movBX,[4321H] b) Explain minimum mode configuration of 8086	10
	c) Explain i) Assume ii) END iii) SEGMENT	
Q.2	a) Draw and explain 8086 Architectureb) Explain in detail interrupts of 8086	08 07
Q.3	a) Explain the following instructions i. MUL ii. LEA iii. IDIV iv. SAHF	08
E SE	b) WAP to transfer the block of 10 bytes using string instructions.	07
Q.4	a) Explain 8255 interfacing with 8086b) Explain keyboard interfacing with 8086	08 07
Q.5	Write short note (any three) a) Pipeline b) PUSH & POP instructions c) memory segmentation d) Instruction format of 8086	15

Section - B

Q.6	Solve any two	10
	a) Explain in details 80286 features	
	b) Explain addressing modes of 8051	320 K
	c) Explain SFR'S in 8051	
Q.7	a) Explain the Protected virtual addressing mode of 8086	08
	b) Draw and explain 80386 Architecture	07
Q.8	a) Explain following Registers of 8051	08
	1. SCON	
	2. IP	EXX
	3. IE	57
	4. B	
	b) Explain in detail memory organization of 8051	07
Q.9	a) Design a 8051 microcontroller based system with	10
	1. 8255	
	2. 8KB EPROM	
	3. 4KB RAM	
	b) WAP to generate a delay of $1 \mu s$ with crystal of $12 MH_Z$ using timer 0 of 8051	05
Q.10	Write short note on (any three)	15
	i. Port 3 of 8051	
	ii. Stepper motor interfacing with 8051	
	iii. T MOD Register	
	iv. Modes of timer in 8051	

[Time: Three Hours]

SUBJECT CODE NO: H-125 FACULTY OF ENGINEERING AND TECHNOLOGY T.E. (EC/ECT/E&C)

Signal Coding & Estimation Theory (REVISED)

Please check whether you have got the right question paper.

[Max.Marks:80]

07

N.B i) Q.No.1 from section A and Q.No.6 from section B are compulsory. ii) Attempt any two questions from the remaining questions in each section Section A 10 Q.1 Write short notes on (any two) a) LZW algorithm b) Lossless channel c) Mutual information & it's properties. a) An analog signal is band limited to 500 KHz. It is sampled at Nyquist rate and samples are Q.2 08 quantized into 4 levels. Each level represents one symbol. Probability of occurrence of these 4 levels (symbols) are $P(x_1) = P(x_4) = \frac{1}{8}$ and $P(x_2) = P(x_3) = 3$ obtain entropy of source and information rate of the source. b) Prove that mutual information of a channel is symmetric i.e. 07 I(x,y) = I(y,x)Q.3 a) Explain Huffman coding Algorithm with one example. 07 b) Apply the Shannon-fano coding procedure for following message group and determine the 08 average length and efficiency of this coded system. M M_0 \mathbf{M}_1 M_4 M_5 M_6 M_7 $\overline{1}/_{16}$ $\overline{1}_{/_4}$

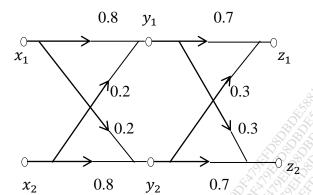
Q.4 a) Compare between Binary symmetric channel and Binary Erasure channel.

b) Two binary symmetrical channels are connected in cascade as shown in figure. Find the channel matrix of resultant channel. Also find $P(z_1)$ and $P(z_2)$ if $P(x_1) = 0.6$ and $P(x_2) = 0.4$

08

10

07



Q.5 a) State and prove channel coding theorem. 07 b) Explain Arithmetic coding with one example. 08

Section B

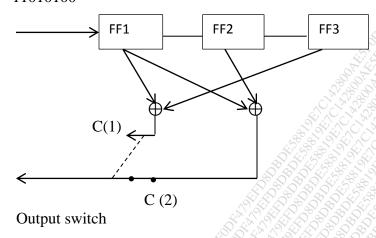
- Q.6 Write short notes on :- (any two) a) Error detection and error correction capability

 - b) Tree diagram and Trellis diagram
 - c) Golay codes & fire codes
- Q.7 a) For a(6,3) linear block code, the coefficient matrix [P] is as follows, 08 The received code words at the receiver are:-
 - 001110 i)
 - ii) 111011

Check whether they are correct or contain errors.

- b) Explain Syndrome decoding for linear codes with neat diagram.
- a) The generator polynomial of a (7, 4). Cyclic code is $g(x) = 1 + x + x^3$. Find the 16 Q.8 08 codewords of this code.
 - 07 b) Explain BCH Codes.

Q.9 a) For the convolutional Encoder shown in figure, Determine the output for input sequence = 08 11010100



- b) Explain Viterbi Decoding Algorithm.
- Q.10 What is Estimation theory? Explain Maximum likely hood Estimation and least square estimation 15 methods.

[Time: Three Hours]

SUBJECT CODE NO:- H-195 FACULTY OF ENGINEERING AND TECHNOLOGY T.E. (EC/ECT/IEC/E&C) Electronics System Design (REVISED)

Please check whether you have got the right question paper.

[Max.Marks:80]

N.B		i) Question no.01 and Question no.06 are compulsory.	D. C.
		ii) Solve any two questions from the remaining questions of each section A and B.	
		iii) Assume suitable components and data wherever necessary.	
		iv) Figures to the right indicate full marks.	
		v) Required data sheet is provided.	
		Section A	
Q.1	Solve	any two	10
Q.1		Explain features of fixed voltage regulator IC 78 XX	10
		Enlist selection criteria for capacitor.	
	,	List the characteristics of opamp.	
	,	List the features, absolute maximum ratings and electrical characteristics of IC temp sensor	
	u)	LM 35.	
Q.2	a)	Outline the procedure to design adjustable regulator using LM 317. How output current is	07
		increased in such regulator.	
	b)	Design the o/p equation of opamp based differentiator.	08
Q.3	a)	Design ckt for light intensity measurement by using photodiode.	07
	b)	Design a bass/treble control ckt using LM 833 with following specifications:	08
	VIII)	$f_B = 20Hz$, $f_T = 12KHz$ and $\pm 20dB$ maximum boost/cut at both ends.	
Q.4	(6) (a)	Design voltage to current amplifier using opamp with following specification	07
<u>,</u>		$I_i = \frac{V_i}{1k\Omega}$, assume grounded load.	
	SO CAN	By using 78540 IC design a step down switching regulator to give the output voltage of 5V	08
		at a maximum load current of 600 mA for input voltage of 10V. The ripple in the output voltage be less than $20mV_{pp}$.	
Q.5	a)	Explain how components R_{INT} , C_{INT} , V_{REF} , C_{AZ} , R_{OSC} , C_{osc} are selected in IC 7106/7107 design.	07
A VIV	b)	Using LM 339 design a Schmitt trigger with following specifications $V_{cc} = 12V$, $V_{OL} = 0V$, $V_{OH} = 5V$, $V_{TL} = 1.5V$, $V_{TH} = 2.5V$	08
1.1 - 1.1	x over the	-Y' M (6Y 4V - V 6Y	

Section B

Q.6	Solve	any two						(8) 2017 F	VX 03.33		10
	a)	Explain	n the feature	s of IC	565.			25.50	J. A. Vigoria	937787968	200
	b)	Draw p	oin diagram	of IC 74	90 and exp	lain in de	etail.		3000	76633344	0,00
		-	n DCB desig	-	-	ircuits.					700
	d)	Explain	n design rule	es for he	at sink.				3 5 5 6 3 5 6 6	100 A V V V V V V V V V V V V V V V V V V	2,00
Q.7	a)	Explain	n finite state	machin	e in detail.	O V	89 89 89				07
	b)	_	DC voltment $50\mu A$, for vertical 400μ			NO 10 0	7 10 77 0	d full scale	deflectio	on current	08
Q.8	a)	Explain	n heat transf	er funda	mentals in	context v	vith elect	ronics circu	it design		07
	b)	range v	vhile keepin	g value	of capacito	r c consta	ant and e	qual to 3600	PF. Als	able to the wide o calculate the ude of the wave	
Q.9	a)	Explain	n exponentia	ıl law of	reliability.				Sylvin		07
	b)		nt failure rate which 10 fai	0 1 . 1 . 1	00 microco	ontroller o	chips are	operated for	a period	d of 1000 hours	08
Q.10	Write	short no	te on	(5, (9, 9))	SAVA OS	3,3,4,6	9 3 3 3 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5				15
	i)	\$\begin{align*} \text{Sign} \t									
	ii)		able multivi			VX 05.05	7620	5 ^y			
	iii)	Sar	nple & hold	circuit	N 25 16 8 2	20 0 4 V	93774				
	3	25 20 85 25 20 85				oata She	et				
	SON TO		Device	Type	Icmax	VcEo	Vcbo	Ptmax	Life min	f_r	
30	549	N. Y. VIV	General Pu	rpose T	ransistors:						
	1, 0, 0, 0, 0, 0, 0, 0, 0, 0, 0, 0, 0, 0,	(1)		S S S	100 mA	^(V) 18 V	18 V	200 MW	200	200 MHz	
		2)	BFY 51	NPN	1 Amp	30 V	60 V	800 MW		50 MHz	
		$\frac{\overline{3}}{3}$	STONE VA.O.	PNP	200 mA	25 V	40 V	300 MW		100 MHz	
		4)	BCY 70	PNP	20 mA	40 V	50 V	300 MW		200 MHz	
2001	\sim \sim \sim \sim \sim		Small Sign	al Trans	sistors:						
06 69 27 69 69	STATE OF	1)		O OY OV	100 mA	45 V	50 V	300 MW	110		
7,00	P P P	Y - Y - V - O 5 2 2	BC 157	V VO.	100 m A	15 V	50 V	300 MW			

3.		Switching to	ransisto	rs:			(8)	VK 03.33	32 2 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3
	1)	2N 2219 A	NPN	800 mA	40 V	75 V	800	75	200 MHz
							MW	3000	5,000
	2)	2N 2905	PNP	600 mA	40 V	60 V	600	150	4 V 10 03 53 53
							MW	13 2 5 6 8 8 X	20 2 4 V V V
4.		RF Transisto	ors.						
١.		2N 2969 A	NPN	200 mA	15 V	40 V	360 MW	40	500 MHz
	,	BFY 90	NPN	50 mA	15 V	87 90 B	200 MW		14 GHz
	,	BC 177	PNP	100 mA	45 V	50 V		75	130 MHz
	,	BC 178	PNP	100 mA	Us, F, VX C	30 V	300 MW	75	130 MHz
				2) 2) 2) 2)	9997	7 V V V V V V V V V V V V V V V V V V V	2, 4, 4, 90, 4,		
5.		Driver Tran	sistors:		55695	25 X V V V		96 8 8 8 W	\$2.000 P
	1)	2N 3053	NPN	700 mA	40 V	60 V	800 MW	125	100 MHz
	2)	2N 2905	PNP	1 A	40 V	5688	600 MW	100	67
			201				1900 N. 4. V.		
6.		Power Tra	nsistor:				25 6 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8	Y Y YOUNGS	
	1)	2N 3055	NPN	15 A	60 V	100 V	115 W	20	1 MHz
	2)	BD 131	NPN	3 A	45 V	70 V	15 W	20	60 MHz
	3)	BD 132	PNP	3 A	45 V	45 V	15 W	20	60 MHz
	4)	TIP 31 A	NPN	3 A	60 V	60 V	40 W	10	8 MHz
	5)	TIP 32 A	PNP	3 A	60 V		40 W		8 MHz
	6)	SL 100	NPN	0.5 A	50 V	2000	4 W	40	
	7)	SK 100	PNP	0.5 A	50 V	13 2 4 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8	4 W	40	
7.	8 8 V	Darlington	Transis	tors:	2 7 7 7 V	22.22.42.			
272	1)	TIP 132	NPN	8 A	100 V	100 V	70 MW	1000	1 MHz
3,75	2)	TIP 137	PNP	8 A	100 V	100 V	70 MW	1000	1 MHz

- 1. Resistor Std. Values $(\Omega, k\Omega, M\Omega, M\Omega, \text{ with fixed values})$: 1.0, 1.1, 1.2, 1.3, 1.5, 1.6, 1.6, 2.0, 2.2, 2.4, 2.7, 3.0, 3.3, 3.6, 3.9, 4.3, 4.7, 5.1, 5.6, 6.2, 6.8, 7.5, 8.2, 9.1.
- 2. Capacitance Values (μF , nF, pF): 0.1, 0.15, 0.22, 0.33, 0.47, 0.60 and multiplies of 10.
- 3. Inductance Values (*H*, *mH*, μ*H*): 1.0, 1.1, 1.2, 1.3, 1.5, 1.6, 1.8, 2.0, 2.2, 2.4, 2.7, 3.0, 3.3, 3.6, 3.9,3.9, 4.7, 5.1, 5.6, 6.2, 6.8, 7.5, 3.2, 9.1

4.	Diodes:			2 P		
	Normal:	Device	e	PIV S	$N \rightarrow N_f$	8 8 8 8 B
		EC 103	3	100 V	3 Amp	3,84,96
		EC 403	3	400 V	3 Amp	1000 00 00 V
	Rectifier:	IN 400	1	50 V	1 Amp	. V 10 0 3 7 5
		IN 400°	7	1000 V	1 Amp	5 5 4 V V V V V V V V V V V V V V V V V
5.	Zener Diodes:	Types No:	V_s	$I_n(mA)$	$Z_n(\Omega)$	$I_m(mA)$
		1N 4370	2.4 V	20	30	150
		1N 4371	2.7 V	20	30	135
		1N 4372	3.0 V	20	29	120
		1N 746	3.3 V	20	20	110
		1N 747	3.6 V	20	24	100
		1N 748	3.9 V	20	~ 23	95
		1N 749	4.3 V	20	22	85
		1N 750	4.7 V	20	19	75

SUBJECT CODE NO:- H-316 FACULTY OF ENGINEERING AND TECHNOLOGY T.E. (EC/ECT/IEC/E&C) Microprocessors & Paripharal

Microprocessors & Peripheral (REVISED)

[Time: Three Hours] [Max.Marks: 80]

Please check whether you have got the right question paper. 1. Q.No.1 & Q.No.6 are compulsory. N.B 2. Solve any two from Q.No.2, Q.No.3, Q.No.4 & Q.No.5. 3. Solve any two from Q.No.7, Q.No.8, Q.No.9 & Q.No.10. 4. Assume suitable additional data if necessary. Section A Attempt any two of the following. Q.1 Explain different software development tools need to be by the programmer. 05 Explain flag structure of 8085 microprocessor. ii) 05 Explain the concept of stack & subroutine. iii) 05 What are the different types of memory mapping? iv) 05 Q.2 a) Write the different addressing modes of 8085. 07 b) Draw the timing diagram of MOV R_1 , R_2 . 08 Q.3 a) Draw & explain pin diagram of 8085. 07 b) Write a program to transfer block of data from one memory location to another. 08 Draw & explain interrupt structure. 07 Q.4 b) Design a fully decoded memory system that provides 2KB of EPROM immediately 08 followed by 4KB of RAM. The EROM starts at address 0000H. a) Write a program to multiply two 8 bit numbers. 07 Q.5 b) Write the classification of memory & explain it. 08

Section B

Q.6	Attem	pt <u>any two</u> of the following.	
	i)	Compare 8155 & 8355	05
	ii)	Write the features of 8255	05
	iii)	Enlist the silent features of 8155.	05
	iv)	Write the difference between serial & parallel data communication.	05
Q.7	a)	With the help of interfacing diagram. Explain LED interfacing with 8255 & write program to turn OFF & ON LED.	07
	b)	With the help of neat diagram explain 0809 interfacing with 8085 to measure analog signals.	. 08
Q.8	a)	Draw & explain the block diagram of 8253.	07
	b)	Interface 8255 with 8085 & explain how you can transmit data bytes parallelly	08
Q.9	a)	Explain speed control of DC motor using microprocessor.	07
	b)	Explain logic analyzer with the help of diagram.	08
Q.10	a)	With the help of neat diagram explain interfacing of stepper motor with $8255 \& write a$ program to rotate a motor in clockwise by 90° .	07
	b)	Explain block diagram of 8355 & write its features.	08

SUBJECT CODE NO:- H-295 FACULTY OF ENGINEERING AND TECHNOLOGY T.E. (EC/ECT/IEC/E&C)

Electromagnetic Engineering (REVISED)

[Time:	Three	Hours	[Max. Marks:	80
N.B		Please check whether you have got the right question paper. i) Q.No.1 and Q.No.6 are compulsory. ii) solve any two questions from Q.2, Q.3, Q.4 and Q.5 in section A iii) solve any two questions from Q.7, Q.8, Q.9 and Q.10 in section iv) figures to the right indicate full marks v)assume suitable data wherever necessary and mention it clearly Section A		
Q.1	Solve	any two		10
		 i. Explain divergence theorem ii. Derive the boundary conditions for a conductor free space interface iii. Explain energy density in an electrostatic field 	***************************************	
Q.2	a.	Given the points $A(x=2, y=3, z=-2)$ and $B(r=8, \theta=25^{\circ} \phi=140^{\circ})$ find i. The spherical coordinates of A; ii. The Cartesian coordinates of B; iii. The distance from A to B;		07
	b.	Derive expression for electric flux density due to i. Point charge ii. Line charge		08
Q.3	a.	In free space let $Q_1 = 10nC$ be at $P_1(0, -4,0)$ and $Q_2 = 20$ nC be at $P_2(0,0)$. Find E at origin		07
	b.\	ii. Where should a $30nC$ point charge be located so that E=0 at the origin A charge of $-0.6\mu C$ is located at A(25, -30,25) and a second charge of $0.7\mu C$ is at B(-12,9,14). find E at origin	ın	08
Q.4	a.	Two uniform line charges $18nC/m$ each are located at x=1, z=2 and at x=-1 space. If the potential at the origin is 200 V find V at P(4,1,3)	, y=2 in free	07
	b.	Calculate the work done in moving a 12C charge from B(2,3,5) to A(4,6,9) i field $15x^2a_x + 15y a_y = V/m$	n the electric	08
Q.5	a.	Given the potential $V = 200(x^2 - y^2)$ and a point $P(2, -1,3)$ that is stipul conductor free space boundary. Find $V, \overline{E}, \overline{D}$ and ρ_s at point p .	ated to lie on a	07
	b.	A point charge $\bar{Q} = 220nC$ is at the origin in free space. Find electric flux de	ensity at $P(1,0,1)$) 08

Section B

Q.6	Solve	any two	10
		i. Discuss Lorentz force equation	5000
		ii. Explain Biot Savart Law	77.76
		iii. Explain significance of loss tangent	5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5
Q.7	a.	A current filament carries a current of $10A$ in the a_z direction on the z axis Find the magnetic field intensity \overline{H} in Cartesian coordinates at a point $P(1,2,3)$ due to this filament if it extends from	07
		i) z=0 to 6 m	
		ii) z= 12 to infinity	
	b.	Region 1 is a semi-infinite space in which $2x - 5y > 0$ while region 2 is defined by $2x - 5y < 0$	08
	-	Let $\mu_{R1} = 2$, $\mu_{R2} = 6$, $H_1 = 10 a_z A/m$	
	Fi	and a) $ B_1 $	
		b) $ B_{N1} $	
		c) H_{t1}	
		d) $ H_2 $	
Q.8	a.	The displacement current density is $15\cos(2\times10^8t-kz)a_x$ $\mu A/m^2$ in a material for which $\sigma=0$, $\varepsilon_r=5$, $\mu_r=4$. Find D and E	07
	b.	Using Amperes circuital Law find \overline{H} due to infinitely long straight conductor along the z axi	s 08
Q.9	a.	A 8375MHz uniform plane wave is propagating in polyethylene with $\varepsilon_r=2.26$, $\mu_r=1$ If the amplitude of electric field intensity is 500 V/m and the material is assumed to be lossless Find	07
	R	i. Phase constant	
	10-0	ii. Wavelength	
	Vy Vie	iii. Velocity	
	3505E	iv. Intrinsic impedance	
Š	(8) (8) (8) (8) (8) (8) (8) (8) (8) (8)	v. Propagation constant	
	b.	Derive the equation of total power in a uniform plane wave by Poynting theorem	08
Q.10	(a.	Write short note on Stokes theorem	07
		Derive the equation of reflection coefficient when the uniform plane wave is incident on boundary between regions composed of two different material	08

SUBJECT CODE NO:- H-267 FACULTY OF ENGINEERING AND TECHNOLOGY T.E. (EC/ECT/IEC/E&C) Feedback Control System (REVISED)

[Time: Three Hours] [Max. Marks: 80]

Please check whether you have got the right question paper.

N.B

- i) Q.No.1 from section A and Q.No.6 from section B are compulsory.
- ii) Attempt any two questions from the remaining questions in each section A/B.
- iii) Assume suitable data if necessary.
- iv) Number indicate in right side indicate full marks.

Section A

Q.1 Solve any two questions.

10

- 1) Explain Hydraulic system.
- 2) Explain signal flow graph rules.
- 3) What is feed forward control system.

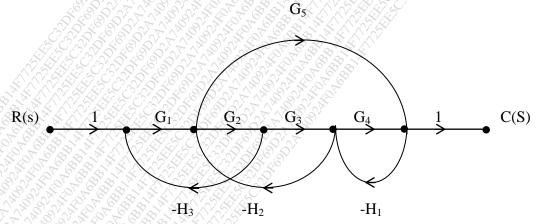
Q.2

a) Explain closed loop and open loop system with two examples each.

08

b) Obtain Transfer function of given figure.

07

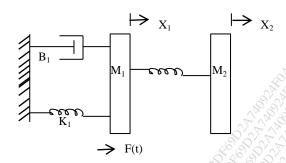


Q.3

a) What is position, velocity and acceleration error constant, for a system.

 $G(s).H(s) = \frac{k}{s^2(s+2)(s+3)}$. Find the value of K to limit the steady state error.

- b) For the mechanical system shown in fig.
 - i) Draw the mechanical network.
 - ii) Write the differential equation of performance.
 - iii) Draw force voltage analogue.



- Q.4 a) Explain time domain specifications.
 - b) For a system G(s). $H(s) = \frac{20 (s+2)}{s^2(s+1)(s+5)}$ determine type of system and steady state error for input $1 + 3t + t^2/2$.
- Q.5 Write a short notes on (Any three)
 - 1) Block diagram reduction rule.
 - 2) DC servomotor
 - 3) Synchro transmitter and Receiver
 - 4) Force voltage analysis.
 - 5) Pneumatic system.

Section B

- Q.6 Solve any two:
 - What is meant by controlability.
 What are the disadvantages of Hurwitz stability criteria.
 - 3) How stability is defined based on information of gain & phase margin .Define Gain phase and margin
- Q.7 a) Determine the stability of $s^6 + 2s^5 + 3s^4 + 12s^3 + 20s^2 + 16s + 16$ using R-H criterion
 - b) Explain different types of stability system.

07

08

07

15

- Q.8 a) Draw the bode plot for follow. And determine gain & phase margin $G(s).H(s) = \frac{10(s+10)}{s(s+2)(s+5)}$
- Q.9 a) Sketch the Nyquist diagram of the unity feedback system where $G(s) = \frac{s+2}{s^2}$
 - b) Evaluate controllability and observability of the system represented in state space model with

$$A = \begin{bmatrix} 0 & 1 & 0 \\ 0 & 0 & 1 \\ 0 & -2 & -3 \end{bmatrix} \text{ and } B = \begin{bmatrix} 0 \\ 0 \\ 0 \end{bmatrix} & \& \ \overline{C} = \begin{bmatrix} 3 & 4 & 1 \end{bmatrix}$$

- Q.10 Write a short notes on (Any three)
 - 1) Root locus design steps.
 - 2) Relays
 - 3) PID controller
 - 4) Fuzzy logic control system
 - 5) Polar plots

SUBJECT CODE NO: H-351 FACULTY OF ENGINEERING AND TECHNOLOGY T.E. (ECT/E&C) Digital Communication

(REVISED)

[Time:	Three	Hours] [Max.Mai	rks:80
N.B		Please check whether you have got the right question paper. 1) Q. No. 1 st and Q. No. 6 are compulsory. 2) Solve any two Questions from the remaining Questions in both sections. SECTION – A	
Q.1	Attem	pt <u>any two</u>	10
	2.	Define the process of Quantization. Explain in brief about uniform quantization. What is aliasing effect? What are the remedies available to avoid aliasing effect? What is aperture effect? How it can be reduced.	
Q.2	a)	State and prove sampling theorem for low pass signal.	08
	b)	Discuss in brief about natural, flat top and ideal sampling.	07
Q.3	a)	A flat top sampling system samples a signal of maximum 1.2 Hz with 2.7 Hz sampling frequency. The duration of the pulse is 0.21sec. Calculate amplitude distortion due to aperture effect at highest signal frequency.	08
	b)	Define companding. Give the compressor characteristic along with different types.	07
Q.4	(a)	What is Delta modulation? Explain in terms of features, drawbacks and application.	07
and the	b)	Explain PCM system in detail.	08
Q.5	Write	short note on	15
	2.	PPM Quantization Noise Random Variables and Stochastic Process.	

SECTION - B

Q.6	Solve <u>any two</u>					
	2.	How PN sequence is related with spread spectrum technique/ Explain in brief. What is raised cosine spectrum in digital communication system. Explain frequency shift keying in detail.				
Q.7	a)	For the input binary sequence $b(k) = \{1, -1, 1, -1, -1, -1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1$	08			
	b)	What is meant by process gain, jam margin, J/S rution and antijam margin? Explain their importance in Spread spectrum communication system.	07			
Q.8	a)	What do you mean by white Gaussian noise/ what is mathematical expression, effect and PDF curve?	07			
	b)	Calculate impulse response of Matched filter.	08			
Q.9	a)	What is MSK, explain with waveform representation.	08			
	b)	Explain DPSK generation and detection	07			
Q.10	Write	short note on:	15			
Sil	2.	ASK, FSK, PSK comparison Optimum filter FHSS technique				

SUBJECT CODE NO: H-420 FACULTY OF ENGINEERING AND TECHNOLOGY T.E. (EC/ECT/IEC/E&C) Digital Signal Processing (REVISED)

[Time: Three Hours] [Max.Marks: 80]

N.B

Please check whether you have got the right question paper.

- i) Q. No. 1 & Q. No. 6 are compulsory from each section A and B respectively
- ii) Solve <u>any two</u> questions <u>from Q. No. 2 to Q. No. 5</u>
- iii) Solve any two questions from Q. No. 7 to Q. No. 10
- iv) Figure to the right indicate full marks
- v) Assume suitable data if necessary

Section A

Q.1 Attempt any two of the following

10

- a) Differentiate between DFT & DTFT
- b) What is aliasing? How do we avoid aliasing?
- c) Overview of signals & system
- d) Relation between Laplace and Z- transform

Q.2

a) Determine the cross correlation of sequences $x(n) = \{---,0,0,2,-1,3,7,1,2,-3,0,0---\}$

08

$$y(n) = \{---,0,0,1,-1,2,-2,4,1,-2,5,0,0---\}$$

b) Find auto-correlation of $x(n) = \{1,3,4,2\}$

07

Q.3 a) State and prove any two properties of Z-transform

07

b) Determine the Z-transform of the following signals

08

- i) $x_1(n) = \{1,2,5,7,0,1\}$
 - ii) $x_2(n) = \{2,4,5,7,0,1\}$
 - iii) $x_3(n) = \delta(n)$
 - iv) $x_4(n) = \delta(n-k), k > 0$

Q.4

a) Find the Fourier transform of the signal

08

 $x(n) = a^n u(n) - 1 < a < 1$ and its magnitude response for a = .9

07

b) State and explain properties of DFT

U.

Q.5	a)	Explain fast convolution techniques overlap add method	07
	b)	Find the IDFT of the given DFT i) $x(k) = \{2,1+j,0,1-j\}$ ii) $x(k) = \{2,2+2j,-2,2-2j\}$	08
		Section B	
Q.6		pt <u>any two</u> of the following	10
	,	Warping effect IIR filter designed by approximation of derivatives	, VQ. (2)
		Magnitude and phase response of digital filters	\$5,
		Product quantization error	
Q.7	a)	Convert the analog filter into digital filter whose system function is	08
Q.7	a)	$H(s) = \frac{s+0.2}{(s+0.2)^2+9} Ts = 1 sec$	00
		Using impulse invariant	
	b)	Explain structure of realization of IIR system	07
Q.8	a)	Explain FIR window filter design by hamming window also draw magnitude & phase plot for LPF using hamming window	07
	b)	Design a FIR high pass filter to meet the following specifications cutoff frequency = $250H_z$ sampling frequency= $fs=1$ KH $_z$ and filter Length= 7	08
Q.9	a)	Explain limit cycle oscillation in recursive system	07
	b)	Explain Gibbs phenomenon in detail	08
Q.10	a)	Design a linear phase FIR filter using Hanning window for the following desired frequency response	08
S		$H_d(w) = \begin{cases} e^{-izw} &, \frac{\pi}{4} \le w \le \pi \\ 0 & \text{otherwise} \end{cases}$	
C. C	b)	Explain concept of frequency wrapping in IIR filter design	07

SUBJECT CODE NO:- H-385 FACULTY OF ENGINEERING AND TECHNOLOGY T.E. (EC/ECT/IEC/E&C) Applies Integrated Circuit & Applications

Analog Integrated Circuit & Applications (REVISED)

[Time: Three I	Hours	[Max. Marks:80]
N.B	Please check whether you have got the right question paper. i) Q. No 1 & Q. No 6 are compulsory. ii) Solve any two questions from Q.2 to Q.5 iii) Solve any two questions from Q.7 to Q.10 iv) Assume suitable data if necessary. Section A	
0.1		10
Q.1 Attem	opt any two Give pin description IC(74) op amp. What are its specifications.	10
2)	Explain voltage to current converter.	
3)	Explain differentiator using op-amp.	
4)	Example sample and hold circuit.	
Q.2 a)	Write neatly about packaging types of IC.	07
b)	What are different measurement parameters of IC(74)? State their typical va	dues. 08
Q.3 a)	With the help of neat circuit diagram, explain analog multiplier	07
b)	Explain voltage follower with neat circuit diagram.	08
Q.4 a)	Explain working of triangular wave generator with its wave form	07
b)	Draw and explain window detector.	08
Q.5 a)	Explain comparator with its characteristics	07
b)	How noise and frequency compensation is achieved in op-amp?	08
	Section B	
1) 2) 3)	pt any two Explain Bi-quad filter. Explain transient response of PLL. What are basics of voltage regulator. Explain adjustable regulator using LM317.	10

Q.7	a) Design first order high pass filter with cut off frequency of 10KHZ and pass band gain of 2	08
	b) Explain Major building blocks of PLL.	07
Q.8	a) Draw and explain Functional block diagram of IC 723 regulator.	07
	b) Draw and explain universal switching regulator using IC 78540	08
Q.9	 a) Explain following terms of PLL 1) Free running frequency . 2) Lock range. 3) Capture range. 	07
	b) Explain second order Butterworth low pass filter.	08
Q.10	a) What is voltage controlled oscillator? Explain block diagram of IC566	07
	b) What are advantages of active Filter? Explain band pass filter with circuit diagram.	08

N.B

SUBJECT CODE NO:- H-105 FACULTY OF ENGINEERING AND TECHNOLOGY T.E. (EC/ECT/IEC/E&C) Power Electronics (REVISED)

[Time: Three Hours] [Max.Marks: 80]

Please check whether you have got the right question paper.

2. Solve any two questions from Q.2 to Q.5 & also any two questions from Q.7 to Q.10.

	Section A	STO O
Q.1	Solve any two:	10
	 i) Step-down cycloconverter ii) Power SCR. iii) Comparison between R & RC triggering. iv) Power factor improvement of converter. 	
Q.2	a) Explain V-I characteristics of TRIAC.b) Explain turning ON & OFF method of SCR with figure.	07
Q.3	a) Explain the effect of source impedance of converter.	07
	b) Explain working of EAC (Excitation Angle Control) mtd. For power factor improvement of converter with fig & waveform.	of 08
Q.4	a) Explain working principle of IGBT with neat diagram & waveform.	07

Q.5 a) An AC voltage controller has resistive load of $R = 10\Omega$, RMS i/p voltage $V_s = 230 V$, 50 Hz. 07 The SCR are switched ON for n = 25, m = 75. Determine

b) Draw & explain all A to F Class commutation techniques in detail.

i) RMS o/p voltage

1. Q.1 & Q.6 are compulsory.

3. Assume suitable data, if necessary.

- ii) i/p power factor
- iii) Average & RMS current rating.
- b) A three phase half wave converter is operated from a 3 \emptyset Y-connected 220V, 50Hz supply & 08 load resistant $R = 10\Omega$. If the average o/p voltage is 25% of maximum possible average vlg. Determine

- i) Delay angle
- ii) RMS & average o/p current
- iii) Average & RMS thyristor current
- iv) Rectifier efficiency
- v) Transformer utilization factor
- vi) i/p power factor.

Section B

Q.6	Solve	any two:	10
	i) ii) iii) iv)		
Q.7	a)	What are the voltage control techniques of an inverter? Also explain why voltage control is essential?	08
	b)	Find out the o/p frequency and attenuation factor of series inverter circuit having following data: $L=10mH$, $C=0.14\mu f$, $R_L=0.4K\Omega$, $to_{ff}=0.2ms$.	07
Q.8	a)	Derive an expression for Io _{max} &Io _{min} for Class 'A' chopper.	08
	b)	A DC chopper (step down) has 'R' load $R = 10\Omega$, i/p voltage $V_s = 200V$. When chopper remains ON, its voltage drop is 2V. chopper frequency is 1KHz. If the duty cycle is 50% determine. i) Average o/p voltage ii) RMS o/p voltage iii) Chopper efficiency iv) Effective i/p resistance.	07
Q.9	a)	For the type 'A'- chopper $V_s=220V$, $F=500$ Hz, $T_{ON}=800$ μ sec, $R=1\Omega$, $L=1mH$, $E=72V$; find i) Whether I_L is continuous or not ii) Compute $I_{max}\&I_{min}$.	08
	b)	Comparison between 180° & 120° conduction mode of $3\emptyset$ inverter.	07
Q.10		Draw & explain voltage commutation chopper with waveform & design consideration. Draw & explain series inverter with waveform in detail.	08 07